

Revision 0.93

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



General Product Information

Product	Application
767 nm DFB Laser	Spectroscopy (K D2 line)
with hermetic 14-Pin Butterfly Housing (ROHS compliant)	Metrology
including Monitor Diode, Thermoelectric Cooler and Thermistor	
with integrated Beam Collimation	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T_{S}	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-40		85
Operational Temperature at Laser Chip	T_LD	°C	10		50
Forward Current	I_{F}	mA			140
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	mW			60
TEC Current	I _{TEC}	Α			1.8
TEC Voltage	V_{TEC}	V			2.8

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T_{case}	°C	-20		65
Operational Temperature at Laser Chip	T_LD	°C	15		35
Forward Current	I _F	mA			130
Output Power	P_{opt}	mW	10		50

Measurement Conditions / Comments	
measured by integrated Thermistor	

Characteristics at T_{LD} = 25° at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	766	767	768
Target Wavelength	λ_{T}	nm		766.7	
Linewidth (FWHM)	Δλ	MHz		0.6	1
Mode-hop free Tuning Range	$\Delta \lambda_{\text{tune}}$	pm	20		
Sidemode Supression Ratio	SMSR	dB	30	50	

Measurement Conditions / Comments
see images on page 4
reached within T _{LD} = 15°35°C at 50 mW
$P_{opt} = 50 \text{ mW}$
reached by current modulation
$P_{opt} = 50 \text{ mW}$



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Characteristics at T _{LD} = 25° a	t BOL				cont'd
arameter	Symbol	Unit	min	typ	max
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.003	
Laser Current @ P _{opt} = 50 mW	I_{LD}	mA			130
Slope Efficiency	η	W/A		0.9	
Threshold Current	I _{th}	mA			70
Divergence parallel (FWHM)	$\Theta_{ }$	0		0.1	
Divergence perpendicular (FWHM)	Θ_{\perp}	0		0.1	
Beam Diameter horizontal	d	mm		1.0	1.2
Beam Diameter vertical	d_\perp	mm		0.8	1.2
Degree of Polarization	DOP	%		60	

Measurement Conditions / Comments
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
$P_{opt} = 50$ mW; E field perpendicular to the base plate

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{opt}	μΑ/mW	0.5		40

Measi	urement Conditions / Comments
$U_R =$	5 V

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U_TEC	V		0.8	
Power Dissipation (total loss at case)	P _{loss}	W		0.4	
Temperature Difference	ΔΤ	K			50

Measurement Conditions / Comments
$P_{opt} = 50 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 50 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 50 \text{ mW}, \Delta T = 20 \text{ K}$
$P_{opt} = 50 \text{ mW}, \Delta T = Tcase - TLD $

,	,				
Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	А			1.1293 x 10	#NV
Steinhart & Hart Coefficient B	В		2.3410 x 10 ^{#NV}		
Steinhart & Hart Coefficient C	C			8.7755 x 10	#NV

Thermistor (Standard NTC Type)

Measurement Conditions / Con	nments
$T_{LD} = 25^{\circ} C$	
$R_1 / R_2 = e^{ \beta (1/T_1 - 1/T_2)} $ at $T_{LD} =$	0° 50° C
$1/T = A + B(\ln R) + C(\ln R)^3$	
T: temperature in Kelvin	
R: resistance at T in Ohm	



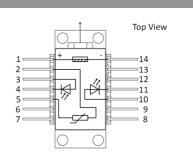
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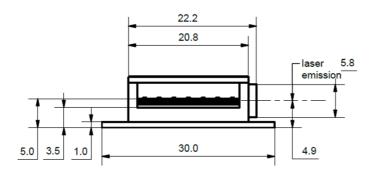


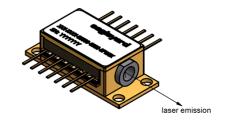
Pin Assignment

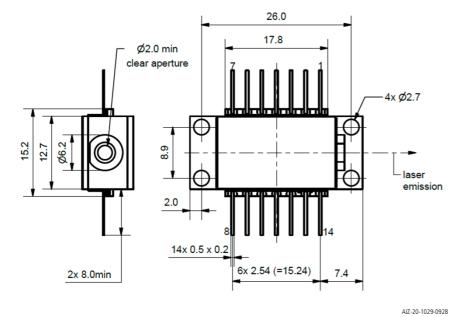
2 Thermistor 13 Case
3 Photodiode (Anode) 12 not connected
4 Photodiode (Cathode) 11 Laser Diode (Cathode)
5 Thermistor 10 Laser Diode (Anode)
6 not connected 9 not connected
7 not connected 8 not connected



Package Drawings







Caution. Excessive mechanical stress on the package can lead to a damage of the laser.

See <u>instruction manual</u> on www.eagleyard.com



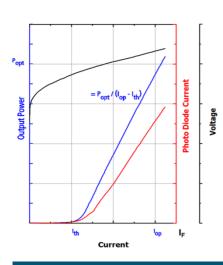
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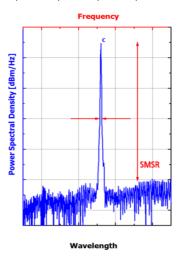


Typical Measurement Results

Output Power vs. Current



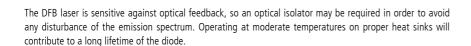
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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